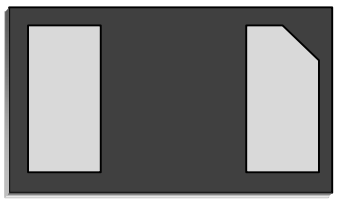
WE5112KF

Transient Voltage Suppressor

Features

- 36 Watts Peak Pulse Power per Line (t_p = 8/20μs)
- Protects one I/O or power line
- Low Clamping Voltage
- Working Voltage: 5 V
- Low Leakage Current



DFN1006-2L

IEC COMPATIBILITY (EN61000-4)

- **IEC 61000-4-2 (ESD) ±12kV (air), ±12kV (contact)**
- **IEC 61000-4-4 (EFT) 40A (5/50ns)**
- **IEC 61000-4-5 (Lightning)3A (8/20μs)**

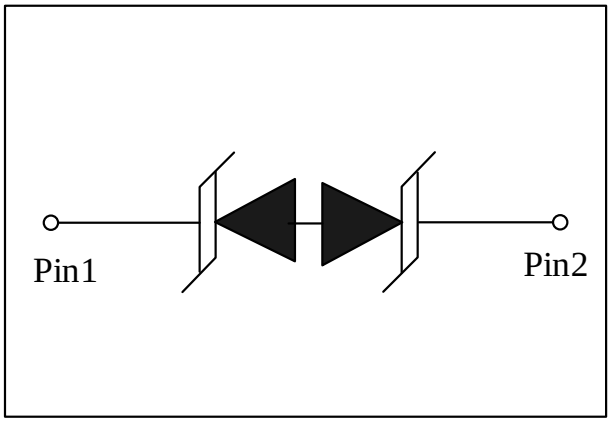
Mechanical Characteristics

- DFN1006-2L package
- Marking : Marking Code
- Packaging : Tape and Reel per EIA 481
- RoHS Compliant & HF
- Device meets MSL1 requirement

Applications

- Laptop Computers
- Cellular Phones
- Digital Cameras
- Personal Digital Assistants (PDAs)

Schematic & PIN Configuration

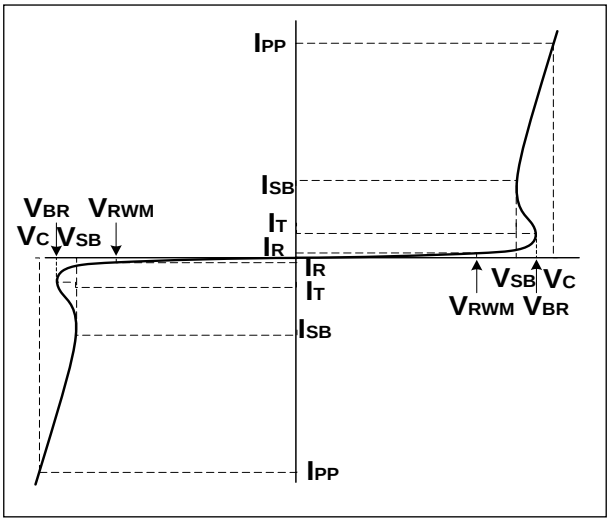


Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power（t_p =8/20μs）	P_{PP}	36	Watts
Peak Pulse Current（t_p =8/20μs）	I_{PP}	3	A
Operating Temperature	T_J	-55 to + 125	℃
Storage Temperature	T_{STG}	-55 to +150	℃

Electrical Parameters

Symbol	Parameter
I_{PP}	Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Reverse Stand-Off Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
V_{SB}	Snap-Back Voltage @ I_{SB}
I_{SB}	Snap-Back Current



Electrical Characteristics (T=25℃ unless otherwise noted)

WE5112KF

Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V_{RWM}				5	V
Reverse Breakdown Voltage	V_{BR}	I_T=1mA	6		9	V
Reverse Leakage Current	I_R	V_{RWM}=5V			500	nA
Clamping Voltage	V_C	I_{PP}=3A,t_p=8/20μs		10.5	12	V
Dynamic Resistance[1,2]	R_{DYN}	TLP=0.2/100ns		0.51		Ω
ESD Clamping Voltage[1]	V_C	IPP = 4A, tp = 0.2/100ns (TLP)		9.2		V
ESD Clamping Voltage[1]	V_C	IPP = 16A, tp = 0.2/100ns (TLP)		15.3		V
Junction Capacitance	C_j	V_R = 0V, f = 1MHz		0.4	0.6	pF

Notes：1、TLP Setting：t_p=100ns, t_r=0.2ns, I_{TLP} and V_{TLP} sample window:t_1=70ns to t_2=90ns.
2、Dynamic resistance calculated from I_{PP}=4A to I_{PP}=16A using “Best Fit”.

Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

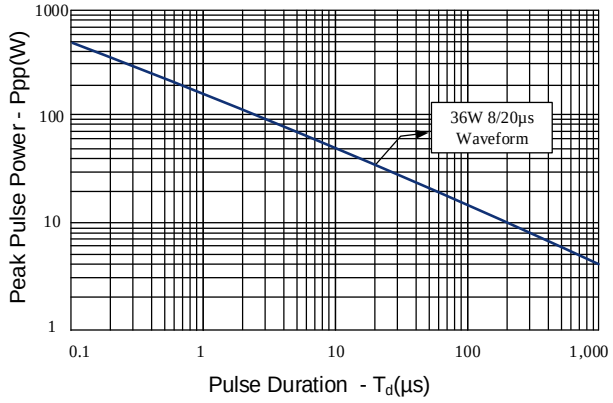


Figure 2: Power Derating Curve

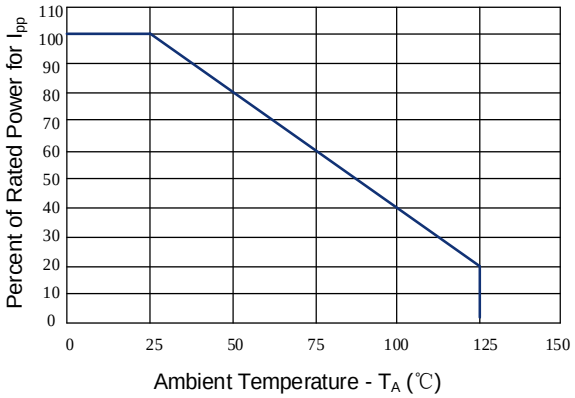


Figure 3: Clamping Voltage vs. Peak Pulse Current

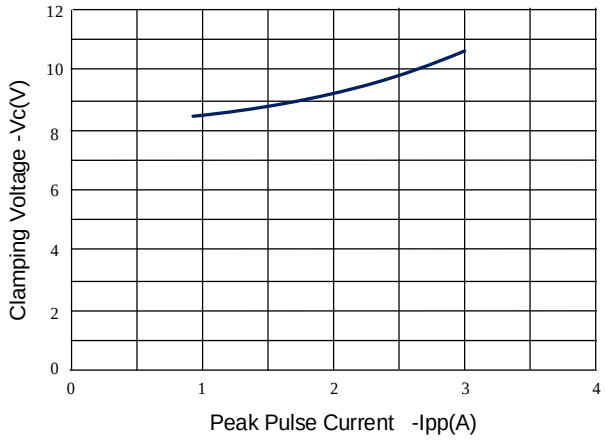


Figure 4: Normalized Junction Capacitance vs. Reverse Voltage

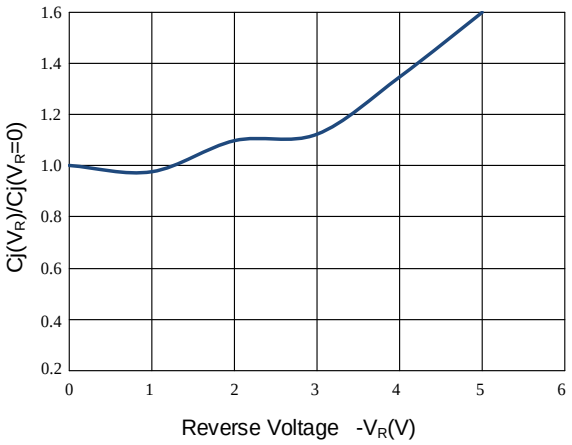


Figure 5: TLP Positive I-V Curve

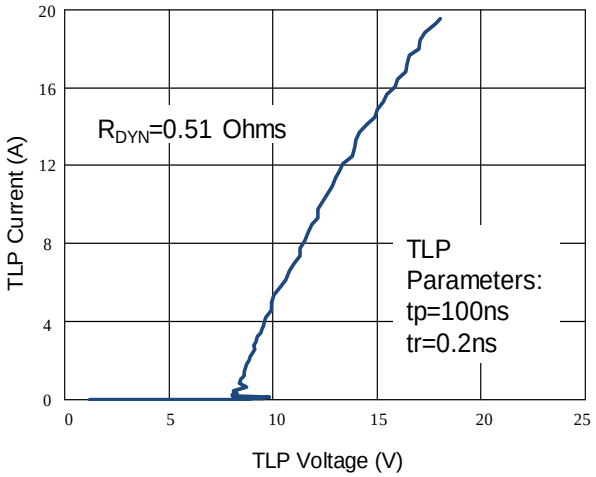
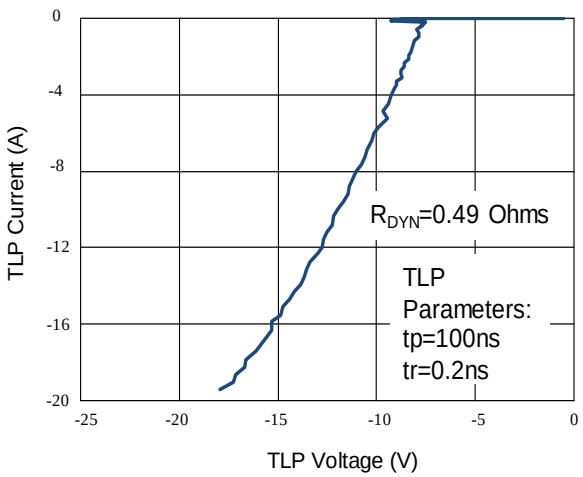
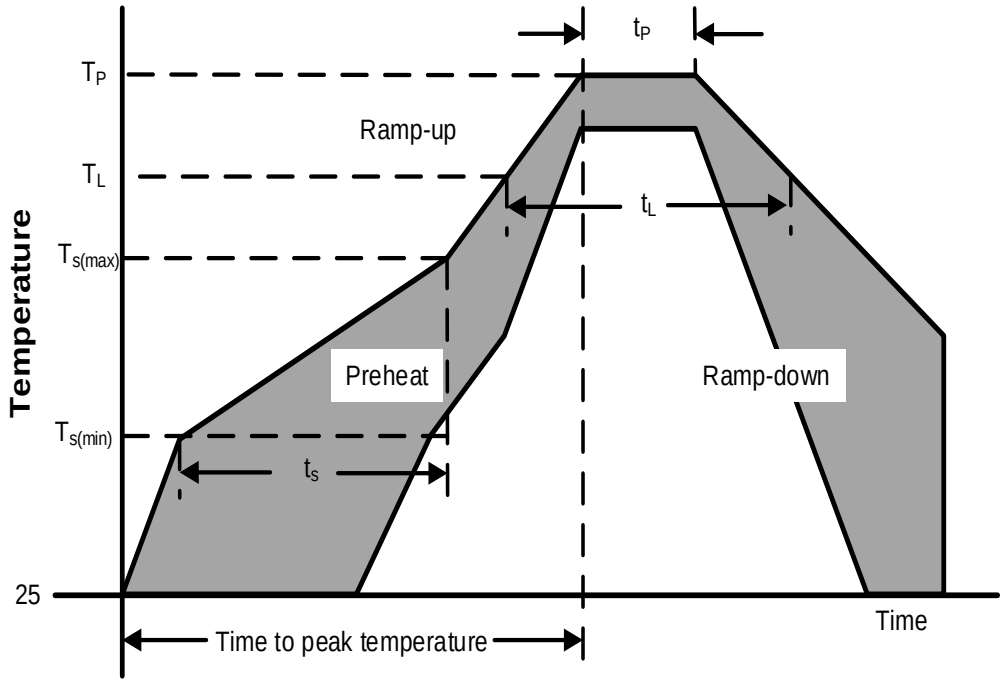


Figure 6: TLP Negative I-V Curve



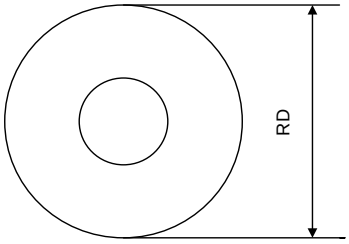
Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	Temperature Min ($T_{s(min)}$)	150°C
	Temperature Max ($T_{s(max)}$)	200°C
	Time (min to max) (ts)	60 – 190 secs
Average ramp up rate (Liquidus Temp) (T_L) to peak		5°C/second max
$T_{S(max)}$ to T_L——Ramp-up Rate		5°C/second max
Reflow	Temperature (T_L) (Liquidus)	217°C
	Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_P)		260+0/-5 °C
Time within actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_P)		8 minutes Max.
Do not exceed		280°C

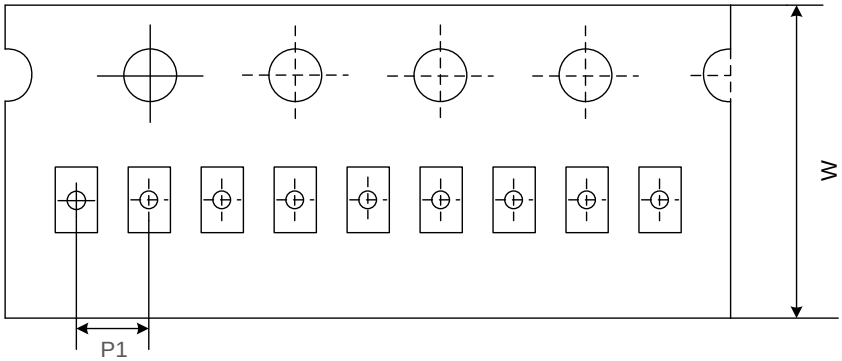


Tape And Reel Information

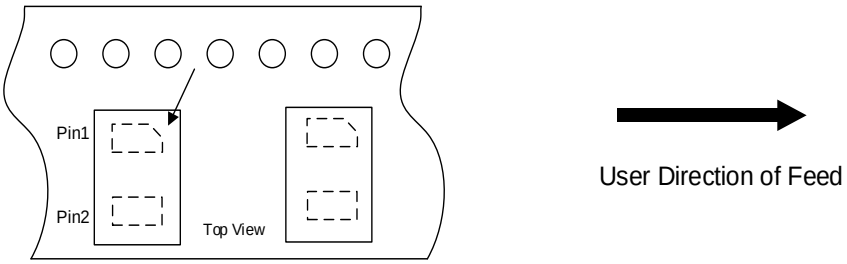
Reel Dimensions



Tape Dimensions



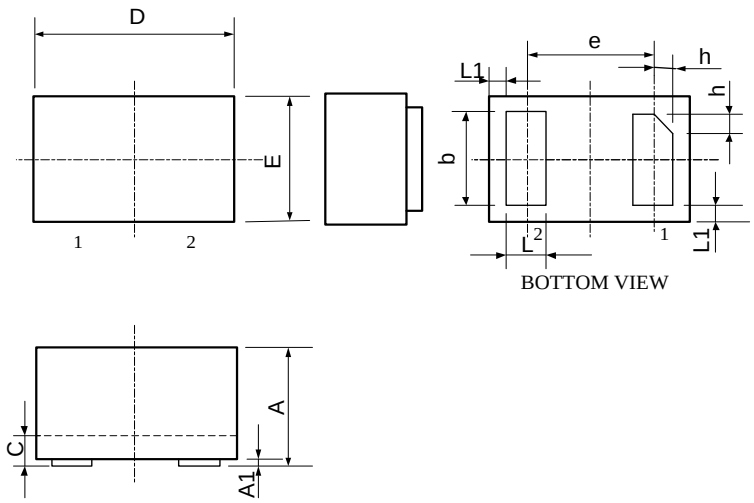
Quadrant Assignments For PIN1 Orientation In Tape

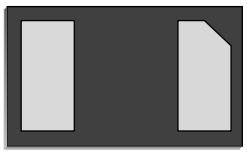


RD	Reel Dimensions	7 inch
W	Overall width of the carrier tape	8 mm
P1	Pitch between successive cavity centers	2mm

Outline Drawing –DFN1006-2L

PACKAGE OUTLINE

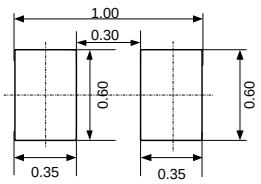




DFN1006-2L

SYMBOL	MILLIMETERS		
	MIN	NOM	MAX
A	0.45	0.50	0.55
A1	0	0.02	0.05
b	0.45	0.50	0.55
C	0.12	0.15	0.18
D	0.95	1.00	1.05
e	0.65BSC		
E	0.55	0.60	0.65
L	0.20	0.25	0.30
L1	0.05REF		
h	0.07	0.12	0.17

Land Pattern



Marking Codes

Part Number	Marking Code
WE5112KF	1 5 T 2

Package Information

Qty：10k/Reel

CONTACT INFORMATION

No.1001, Shiwan (7) Road, Pudong District, Shanghai, P.R.China.201207
Tel: 86-21-68969993 Fax: 86-21-50757680 Email: market@way-on.com
WAYON website: **http://www.way-on.com**
For additional information, please contact your local Sales Representative.

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Specifications are subject to change without notice.
The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time.
Users should verify actual device performance in their specific applications.